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LIST OF SYMBOLS AND ABBREVIATIONS

ZT	Dimensionless figure of merit
Z	Figure of merit
T	Absolute temperature
S	Seebeck coefficient
ρ	Electrical resistivity
σ	Electrical conductivity
P	Power factor
n	Carrier concentration
μ	Carrier mobility
k_B	Boltzmann constants
d	Film thickness
I	Electrical current
B	Magnetic field
q	Carrier charge
DC	Direct current
FE-SEM	Field-emission scanning electron microscopy
Ag-Sb-Te	Silver-Antimony-Tellurium
AST	Ag-Sb-Te
AFM	Atomic force microscopy
EDX	Energy dispersive X-ray spectroscope
GIXRD	Grazing-incidence X-ray diffraction
S	Seebeck coefficient
PF	Power factor
V_{output}	Output voltage
P_{max}	Maximum output power
R_{in}	Internal resistance
R_L	External electrical load resistance